

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

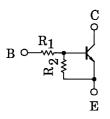
RN1314,RN1315,RN1316 RN1317,RN1318

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

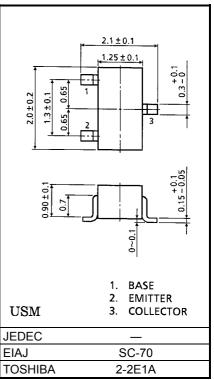
Unit: mm

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2314~RN2318

Equivalent Circuit and Bias Resister Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN1314	1	10
RN1315	2.2	10
RN1316	4.7	10
RN1317	10	4.7
RN1318	47	10



Weight: 0.006g

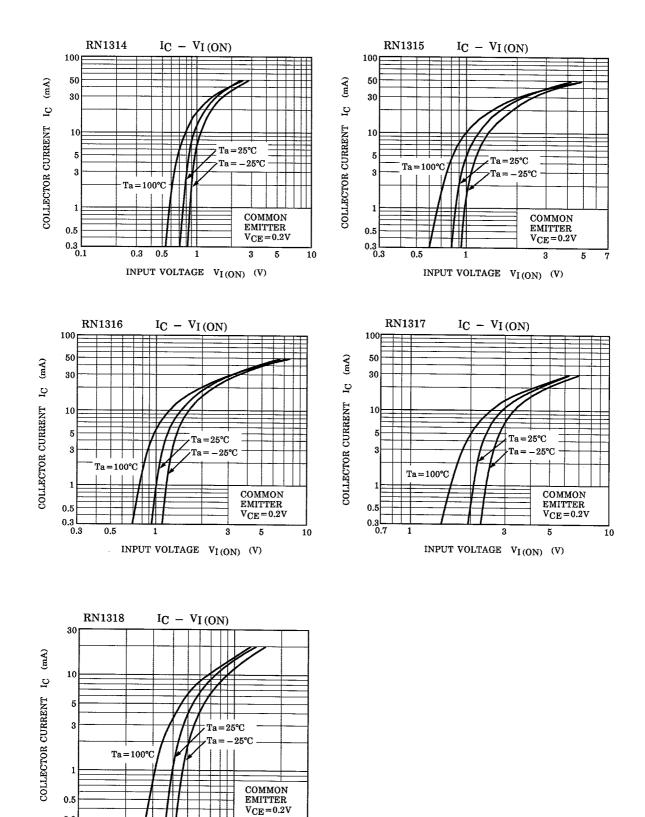
Maximum Ratings (Ta = 25°C)

Characterist	Symbol	Rating	Unit		
Collector-base voltage	RN1314~1318	V _{CBO}	50	V	
Collector-emitter voltage		V _{CEO}	50	V	
Emitter-base voltage	RN1314		5	V	
	RN1315		6		
	RN1316	V _{EBO}	7		
	RN1317		15		
	RN1318		25		
Collector current		Ι _C	100	mA	
Collector power dissipation	RN1314~1318	P _C	100	mW	
Junction temperature	KIN 13 14~13 18	Tj	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN1314~1318	I _{CBO}		V _{CB} = 50V, I _E = 0	-	_	100	nA
	RN1314~1318	ICEO		V _{CE} = 50V, I _B = 0	_	_	500	nA
Emitter cut-off current	RN1314	I _{EBO}	_	V _{EB} = 5V, I _C = 0	0.35	_	0.65	mA
	RN1315			V _{EB} = 6V, I _C = 0	0.37	_	0.71	
	RN1316			V _{EB} = 7V, I _C = 0	0.36	_	0.68	
	RN1317			V _{EB} = 15V, I _C = 0	0.78	_	1.46	
	RN1318			V _{EB} = 25V, I _C = 0	0.33	_	0.63	
DC surrent agin	RN1314~16,18			N/ 51/1 40 A	50	_		
DC current gain	RN1317	h _{FE}	_	V _{CE} = 5V, I _C = 10mA	30	_	_	
Collector-emitter saturation voltage	RN1314~1318	V _{CE (sat)}	_	I _C = 5mA, I _B = 0.25mA	_	0.1	0.3	V
	RN1314				0.6	-	2.0	V
	RN1315				0.7	—	2.5	
Input voltage (ON)	RN1316	V _{I (ON)}	—	V _{CE} = 0.2V, I _C = 5mA	0.8	—	2.5	
	RN1317				1.5	_	3.5	
	RN1318				2.5	_	10.0	
Input voltage (OFF)	RN1314	VI (OFF)		V _{CE} = 5V, I _C = 0.1mA	0.3	—	0.9	V
	RN1315		_		0.3	—	1.0	
	RN1316				0.3	—	1.1	
	RN1317				0.3	_	2.3	
	RN1318				0.5	_	5.7	
Transition frequency	RN1314~1318	f _T	—	V _{CE} = 10V, I _C = 5mA	_	250		MHz
Collector Output capacitance	RN1314~1318	C _{ob}	_	V _{CB} = 10V, I _E = 0, f = 1MHz	-	3.0	6.0	pF
	RN1314			_	0.7	1.0	1.3	kΩ
Input resistor	RN1315				1.54	2.2	2.86	
	RN1316	R ₁	_		3.29	4.7	6.11	
	RN1317				7.0	10.0	13.0	
	RN1318				32.9	47.0	61.1	
Resistor ratio	RN1314		_	_	_	0.1		
	RN1315				_	0.22	_	
	RN1316	R_1/R_2			_	0.47	_	
	RN1317				_	2.13	—	
	RN1318				_	4.7	_	

0.5 0.3 1



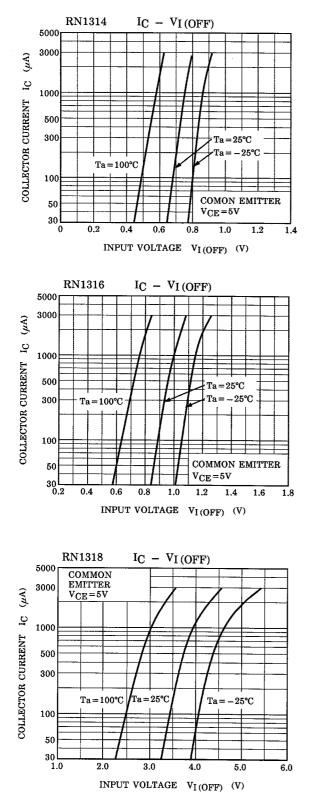
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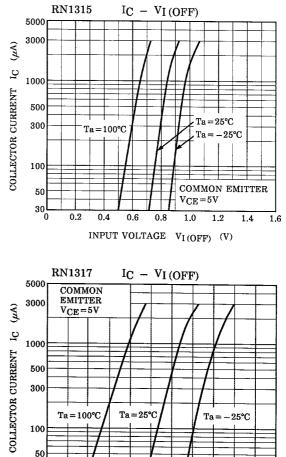
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5 INPUT VOLTAGE $V_{I(ON)}$ (V)

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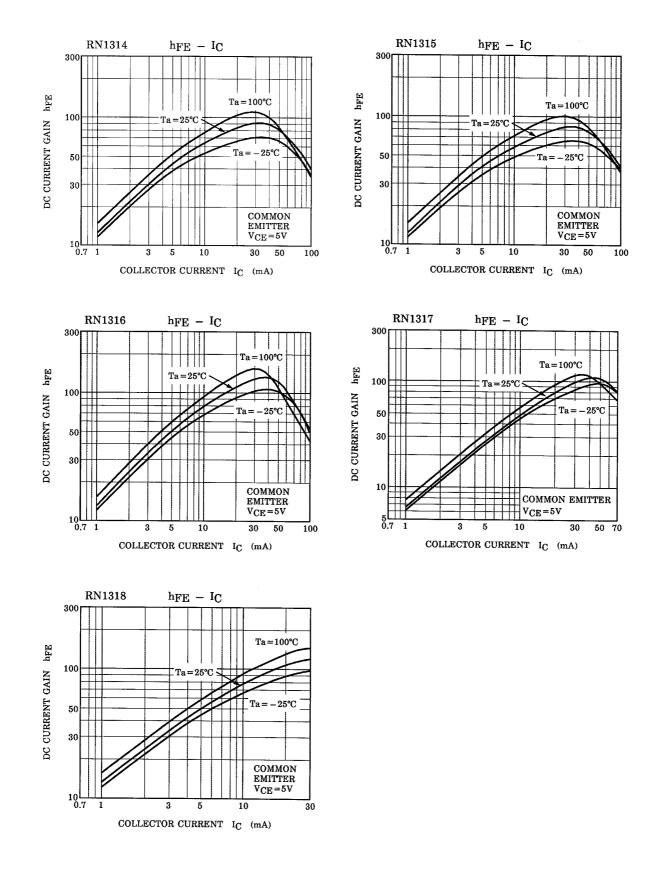


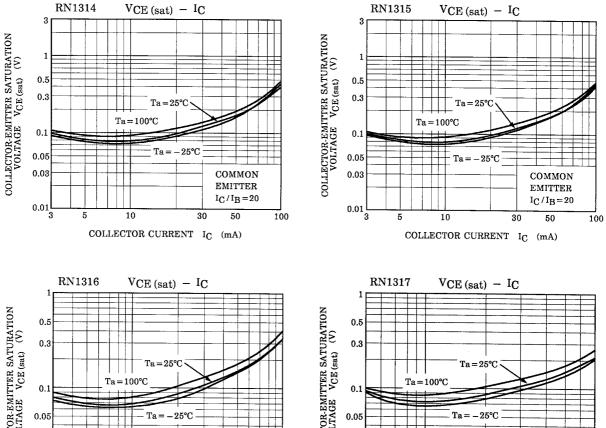
1.2 1.6 2.0 2.4 2.8

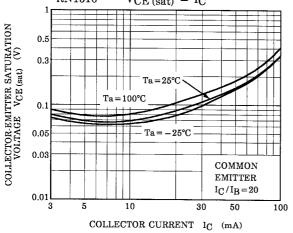
30L 0.8

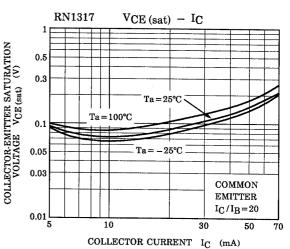
INPUT VOLTAGE $V_{I(OFF)}$ (V)

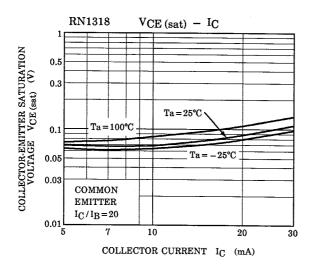
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Type Name	Marking
RN1314	X Q H H
RN1315	X S H
RN1316	X T U
RN1317	X U H
RN1318	XW IIII

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